

NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE01P35K uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

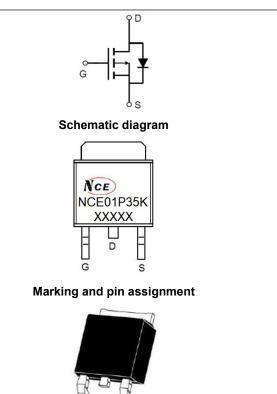
General Features

- V_{DS} =-100V,I_D =-35A
 R_{DS(ON)} <40mΩ @ V_{GS}=-10V (Typ:30mΩ)
 R_{DS(ON)} <45mΩ @ V_{GS}=-4.5V (Typ:32mΩ)
- Super high dense cell design
- Advanced trench process technology
- Reliable and rugged
- High density cell design for ultra low On-Resistance

Application

• Portable equipment and battery powered systems

100% UIS TESTED! 100% ΔVds TESTED!



TO-252-2L top view

Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|-----------|----------------|-----------|------------|----------|
| NCE01P35K | NCE01P35K | TO-252-2L | - | - | - |

Absolute Maximum Ratings (Tc=25℃unless otherwise noted)

| | / | / | | |
|--|----------------------------------|------------|------|--|
| Parameter | Symbol | Limit | Unit | |
| Drain-Source Voltage | Vds | -100 | V | |
| Gate-Source Voltage | Vgs | ±20 | V | |
| Drain Current-Continuous | ID | -35 | A | |
| Drain Current-Continuous(Tc=100°C) | l₀ (100°C) | -24.7 | A | |
| Pulsed Drain Current | I _{DM} | -140 | A | |
| Maximum Power Dissipation | PD | 110 | W | |
| Single pulse avalanche energy (Note 5) | Eas | 368 | mJ | |
| Derating factor | | 0.73 | W/°C | |
| Operating Junction and Storage Temperature Range | T _J ,T _{STG} | -55 To 175 | °C | |

Thermal Characteristic

| Thermal Resistance, Junction-to-Case (Note 2) | R _{eJC} | 1.36 | °C/W |
|--|------------------|------|------|
| Thermal Resistance, Junction-to-Ambient (Note 4) | R _{0JA} | 50 | °C/W |



Electrical Characteristics (Tc=25°C unless otherwise noted)

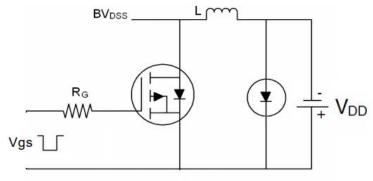
| Parameter | Symbol | Condition | Min | Тур | Мах | Unit |
|------------------------------------|---------------------|--|------|------|------|----------|
| Off Characteristics | l. | - | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =-250µA | -100 | - | - | V |
| Zero Gate Voltage Drain Current | IDSS | V _{DS} =-100V,V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V _{GS} =±20V,V _{DS} =0V | - | - | ±100 | nA |
| On Characteristics (Note 3) | · | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} ,I _D =-250µA | -1.5 | -1.8 | -2.5 | V |
| Drain Source On State Registeres | | V _{GS} =-10V, I _D =-20A | - | 30 | 40 | mΩ |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =-4.5V, I _D =-20A | - | 32 | 45 | mΩ |
| Forward Transconductance | g⊧s | V _{DS} =-10V,I _D =-20A | - | 50 | - | S |
| Dynamic Characteristics (Note4) | | · | · | | | |
| Input Capacitance | C _{lss} | - V _{DS} =-50V,V _{GS} =0V, | - | 5720 | - | pF |
| Output Capacitance | Coss | | - | 190 | - | pF |
| Reverse Transfer Capacitance | C _{rss} | F=1.0MHz | - | 128 | - | pF |
| Switching Characteristics (Note 4) | · | | | | | |
| Turn-on Delay Time | t _{d(on)} | V _{DD} =-50V,I _D =-20A V _{GS} =-10V,R _{GEN} =9.1Ω | - | 17 | - | nS |
| Turn-on Rise Time | tr | | - | 80 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | | - | 45 | - | nS |
| Turn-Off Fall Time | t _f | | - | 65 | - | nS |
| Total Gate Charge | Qg | - V _{DS} =-50V,I _D =-20A, V _{GS} =-10V | - | 118 | - | nC |
| Gate-Source Charge | Qgs | | - | 19.8 | - | nC |
| Gate-Drain Charge | Q _{gd} | VGS=-10V | - | 22.2 | - | nC |
| Drain-Source Diode Characteristics | · | | · | | | <u>.</u> |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =-20A | - | - | -1.2 | V |
| Diode Forward Current (Note 2) | Is | - | - | - | -35 | A |
| Reverse Recovery Time | t _{rr} | TJ = 25°C, IF =-20A | - | 90 | - | nS |
| Reverse Recovery Charge | Qrr | di/dt = 100A/µs ^(Note3) - 145 - | | | nC | |
| Forward Turn-On Time | t _{on} | Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD | | | | |
| | | | | | | |

Notes:

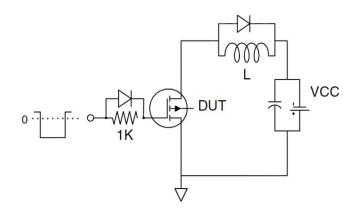
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. The value of R_{BJA} is measured with the device mounted on $1in^2$ FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^{\circ}$ C. The value in any given application depends on the user's specific board design, and the maximum temperature of 150° C may be used if the PCB allows it.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition: Tj=25 $^\circ C$,V_DD=-50V,V_G=-10V,L=0.5mH,Rg=25 Ω



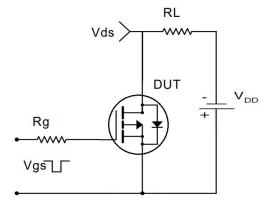
Test Circuit 1) E_{AS} test Circuit



2) Gate charge test Circuit

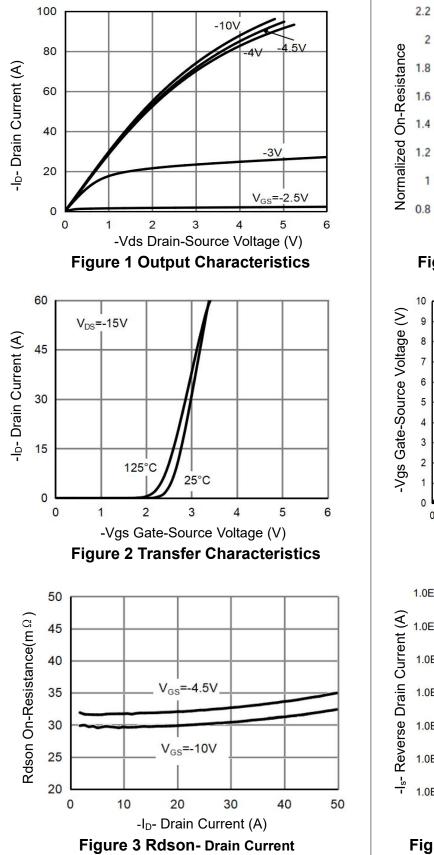


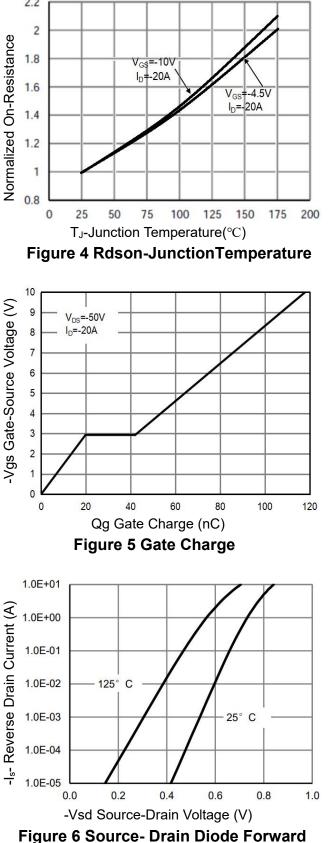
3) Switch Time Test Circuit





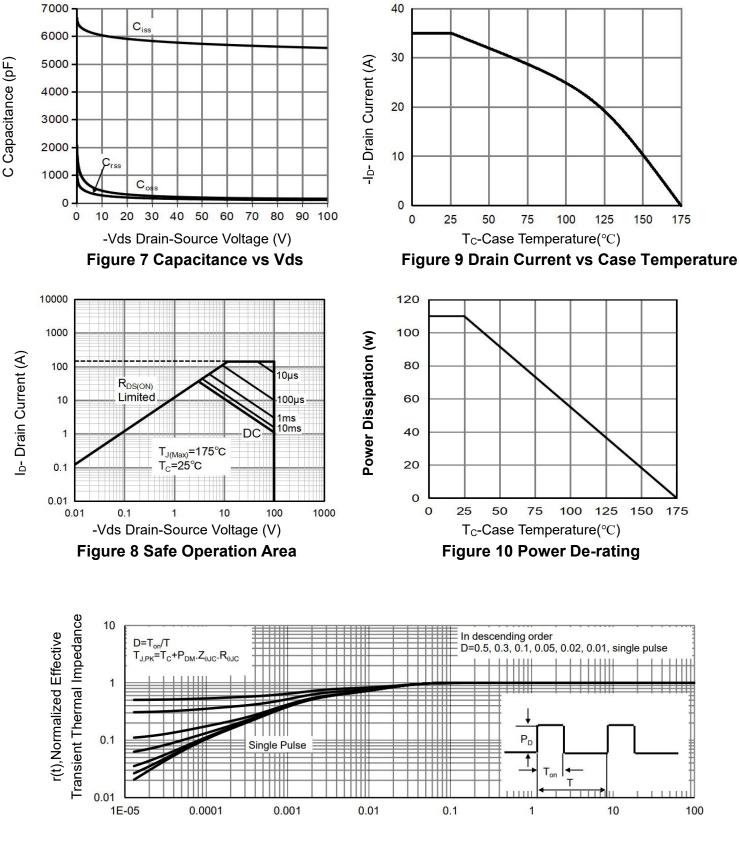
Typical Electrical and Thermal Characteristics (Curves)







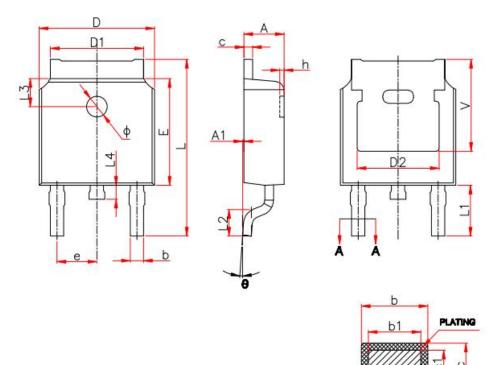
http://www.ncepower.com



Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance



TO-252-2L Package Information



BASE METAL

SECTION A-A

Millimeters Symbol Min. Max. 2.20 2.40 A 0.13 A1 0.00 0.66 0.86 b b1 0.73 0.79 С 0.46 0.58 c1 0.50 0.52 6.50 6.70 D 5.10 5.46 D1 D2 4.83 REF. E 6.00 6.20 2.39 2.19 е 9.80 10.40 L 2.90 REF. L1 1.70 L2 1.40 L3 1.60 REF. L4 0.60 1.00 Φ 1.10 1.30 θ 0° 8° h 0.00 0.30 5.35 REF. V



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